TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

# **TD62387AFN,TD62388AFN**

#### 8CH LOW INPUT ACTIVE DARLINGTON SINK DRIVER

The TD62387AFN and TD62388AFN are non-inverting transistor arrays, which are comprised of eight NPN darlington output stages and PNP input stages.

All unites feature integral clamp diodes for switching inductive

These devices are Low Level input active drivers and are suitable for operations with TTL, 5 V CMOS and 5 V Microprocessor which have sink current output drivers.

Applications include relay, hammer, lamp and LED driver.



:SSOP20 pin (0.65 mm pitch) Package Type

High Sustaining Voltage : 50 V (Min)

Output Current (Single Output): 500 mA / ch (Max)

Output Clamp Diodes

:LOW LEVEL ACTIVE Input

Standard Supply Voltage

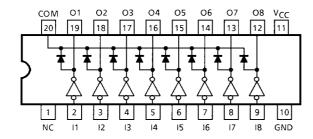
Inputs Compatible with TTL and 5 V CMOS

TYPE	V <sub>IN(ON)</sub>
TD62387AFN	0 V~V <sub>CC</sub> - 3.7 V
TD62388AFN	0 V V CC 5.7 V

# SSOP20-P-225-0.65A

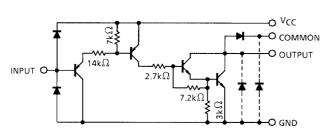
Weight: 0.09 g (Typ.)

# PIN CONNECTION (TOP VIEW)

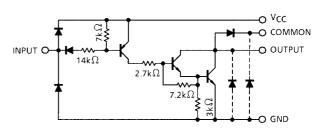


#### **SCHEMATICS (EACH DRIVER)**

TD62387AFN



#### TD62388AFN



The input and output parasitic diodes cannot be used as clamp diodes.



# MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	V <sub>CC</sub>	-0.5~7.0	V	
Output Sustaining Voltage	V <sub>CE</sub> (SUS)	-0.5~50	٧	
Output Current	lout	500	mA / ch	
Input Voltage	V <sub>IN</sub>	-0.5~7.0	V	
Input Current	I <sub>IN</sub>	-10	mA	
Clamp Diode Reverse Voltage	V <sub>R</sub>	50	V	
Clamp Diode Forward Current	I <sub>F</sub>	500	mA	
Power Dissipation	PD	0.96 (Note)	W	
Operating Temperature	T <sub>opr</sub>	-40~85	°C	
Storage Temperature	T <sub>stg</sub>	-55~150	°C	

Note: On Glass Epoxy PCB (50 × 50 × 1.6 mm Cu 40%)

# RECOMMENDED OPERATING CONDITIONS (Ta = $-40 \sim 85$ °C)

CHARACTERISTIC	SYMBOL	CONDITION		MIN	TYP.	MAX	UNIT
Supply Voltage	V <sub>CC</sub>			4.5	5.0	5.5	V
Output Sustaining Voltage	V <sub>CE</sub> (SUS)		0	_	50	V	
Output Current	I <sub>OUT</sub> (Note)	DC 1 Circuit		0	_	350	
		$T_{pw}$ = 25 ms 8 Circuits Ta = 85°C $T_j$ = 120°C	Duty = 10%	0	_	180	mA / ch
			Duty = 50%	0	_	90	
Input Voltage	V <sub>IN</sub>			0	_	5.5	V
Clamp Diode Reverse Voltage	V <sub>R</sub>			_	_	50	V
Clamp Diode Forward Current	I <sub>F</sub>			_	_	400	mA
Power Dissipation	P <sub>D</sub>			_	_	0.4	W

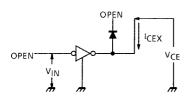
Note: On Glass Epoxy PCB (50 × 50 × 1.6 mm Cu 40%)

# **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

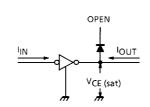
CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Output Leakage Current		I <sub>CEX</sub>	1	V <sub>CC</sub> = 5.5 V, I <sub>IN</sub> = 0 V <sub>OUT</sub> = 50 V, Ta = 85°C	_	_	100	μΑ	
Output Saturation Voltage		V <sub>CE</sub> (sat)	2	V <sub>CC</sub> = 4.5 V V <sub>IN</sub> = V <sub>IN</sub> (ON) Max. I <sub>OUT</sub> = 350 mA	_	1.4	2.0	V	
Input Current	Output On	I <sub>IN (ON)</sub>	3	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0.4 V	_	-0.32	-0.45	mA	
				$V_{CC} = 5.5 \text{ V}, V_{IN} = -20 \text{ V}$	_	_	-2.6		
	Output Off	I <sub>IN (OFF)</sub>	4		_	_	-4.0	μA	
Input Voltage (Output on)		V <sub>IN (ON)</sub>	5		_	_	V <sub>CC</sub> - 3.7	V	
Clamp Diode Reverse Current		I <sub>R</sub>	6	V <sub>R</sub> = 50 V, Ta = 25°C (Note 1)	_	_	50	μА	
				V <sub>R</sub> = 50 V, Ta = 85°C (Note 1)	_	_	100		
Clamp Diode Forward Current		V <sub>F</sub>	7	I <sub>F</sub> = 350 mA	_	_	2.0	V	
				I <sub>F</sub> = 280 mA	_	_	1.8	v	
Supply Current		I <sub>CC</sub> (ON)	- 8	V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = 0	_	17	22	mA	
		I <sub>CC</sub> (OFF)		V <sub>CC</sub> = 5.5 V, V <sub>IN</sub> = V <sub>CC</sub>	_	_	100	μΑ	
Turn-On Delay		t <sub>ON</sub>	9	V <sub>CC</sub> = 5 V, V <sub>OUT</sub> = 50 V(Note1)	_	0.1		μs	
Turn-Off Delay		t <sub>OFF</sub>	9	$R_L = 125 \Omega$ , $C_L = 15 pF$	_	3	_		

# **TEST CIRCUIT**

1. I<sub>CEX</sub>

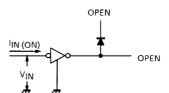


2. VCE (sat)

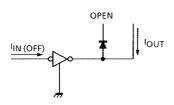


3. I<sub>IN (ON)</sub>

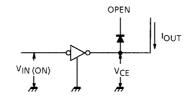
6. I<sub>R</sub>

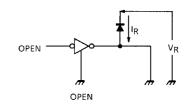


4. I<sub>IN</sub> (OFF)

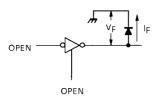


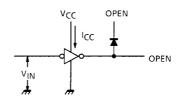
5. V<sub>IN (ON)</sub>





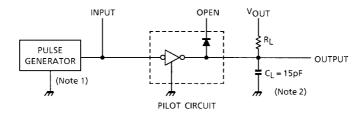
7. V<sub>F</sub>

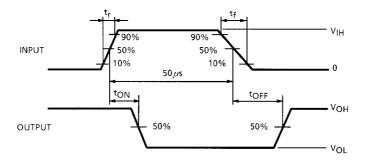




8. Icc

### 9. ton, toff





Note 1: Pulse Width 50  $\mu s$ , Duty Cycle 10%

Output Impedance 50  $\Omega$ ,  $t_{\Gamma} \le 5$  ns,  $t_{f} \le 10$  ns

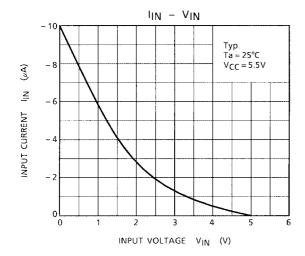
Note 2: C<sub>L</sub> includes probe and jig capacitance.

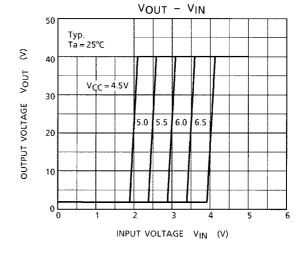
#### PRECAUTIONS for USING

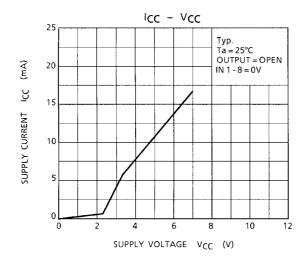
This IC does not integrate protection circuits such as overcurrent and overvoltage protectors.

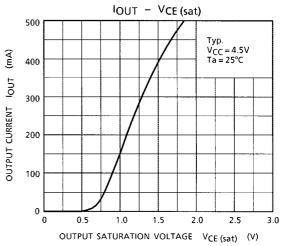
Thus, if excess current or voltage is applied to the IC, the IC may be damaged. Please design the IC so that excess current or voltage will not be applied to the IC.

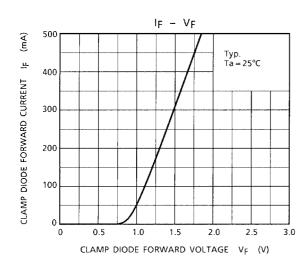
Utmost care is necessary in the design of the output line, VCC, COMMON and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



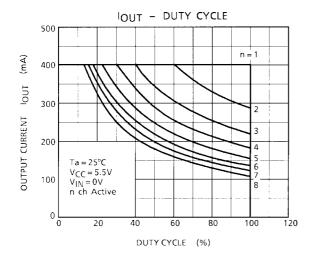


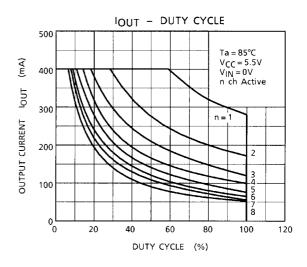


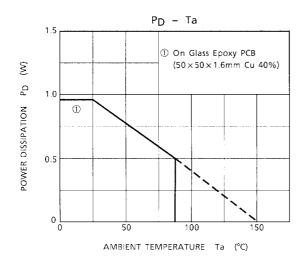




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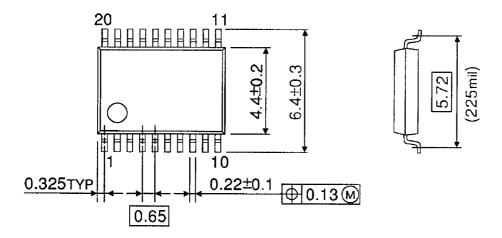


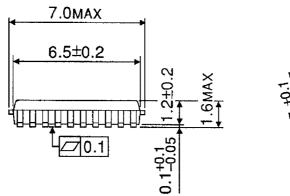


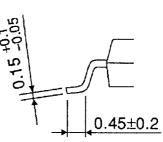


### **PACKAGE DIMENSIONS**

SSOP20-P-225-0.65A Unit: mm







Weight: 0.09 g (Typ.)

## RESTRICTIONS ON PRODUCT USE

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